

PATENT NUMBER and ISSUE DATE

U.S. UTILITY Patent Application

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10017389	FILING DATE		SUBCLASS	1	EXAMINER	
10017389	12 18/2001	257		2811	,	
**APPLICANTS: Nobuyuki, Ohnak	ka Kiyoshi				awaguchi Yasutoshi. Otsu	ka
FOREIGN APPI APAN 2000-3866		RIFIED:	yen ou	H		
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TLE: Method for	fabricating semi	conductor	method for fo	bricatio	g semiconductor substrat	
miconductor light	emitting device			- 71011111		1
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TICE OF ALLOWANCE MAILED					CLAIMS A	LLOWED
		Assists	nt Examine:		Total Claims	Print Claim O.G
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NOTICE OF ALLOWANCE MAILED			CLAIMS ALLOWED					
		Assistant Examine:	Total Claims		Print Claim for O.G			
ISSUE FEE			DRAWING					
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		Primary Examiner						
TERMINAL		PREPARED FOR ISSUE	Application Examiner					
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